

STTH1008DTI

800 V tandem hyperfast diode

Datasheet - production data

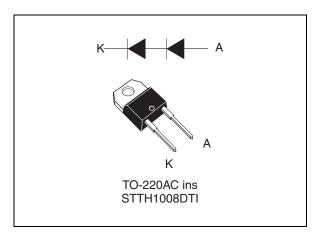


Table 1. Device summary

I _{F(AV)}	10 A
I _{FRM}	20 A
V _{RRM}	800 V
t _{rr}	40 ns
I _{RM}	8.5 A
V _F	1.7 V
Tj	150 °C

Features

- High voltage rectifier
- Tandem diodes in series
- · Very low switching losses
- Insulated device with internal ceramic
- Equal thermal conditions for both 400 V diodes
- Static and dynamic equilibrium of internal diodes are warranted by design

Description

The STTH1008DTI is an ultrahigh performance diode composed of two 400 V dice in series.

Characteristics STTH1008DTI

1 Characteristics

Table 2. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage	800	V	
I _{F(RMS)}	Forward rms current		16	Α
I _{F(AV)}	Average forward current, $\delta = 0.5$	T _c = 85 °C	10	Α
I _{FRM}	Repetitive peak forward current	$T_c = 135 ^{\circ}\text{C}, \delta = 0.3$	20	Α
I _{FSM}	Surge non repetitive forward current	120	Α	
T _{stg}	Storage temperature range		-65 to +175	°C
T _j	Maximum junction temperature	150	°C	

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	2.5	°C/W

Table 4. Static electrical characteristics

Symbol	Parameters	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	L (1) Payaraa laakaga ayrrant		V V			20	
I _R ⁽¹⁾ Reverse leakage current	Reverse leakage current	T _j = 150 °C	$V_R = V_{RRM}$		20	200	μΑ
		T _c = 25 °C	I _F = 10 A		2.15	2.5	V
V _F ⁽²⁾	Forward voltage drop	T _c = 150 °C			1.7	2.05	
V _F ··/ Folwaid	Forward voltage drop	T _c = 25 °C	I = 20 A		2.45	2.85	V
		T _c = 150 °C	I _F = 20 A		2.05	2.45	

^{1.} Pulse test: $t_P = 5$ ms, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 1.65 \times I_{F(AV)} + 0.04 \times I_{F^{2}(RMS)}$$

^{2.} Pulse test: t_P = 380 μ s, δ < 2%

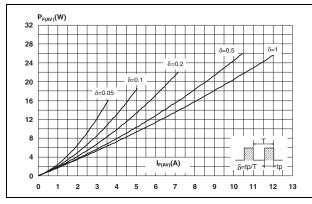
STTH1008DTI Characteristics

Table 5. Dynamic electrical characteristics

Symbol	Parameters	-	Min.	Тур	Max.	Unit	
I _{RM}	Reverse recovery current	T _i = 125 °C	$T_j = 125 ^{\circ}\text{C}$ $I_F = 10 \text{A}, V_R = 400 \text{V}, \\ dI_F/dt = -200 \text{A/}\mu\text{s}$		8.5	11.5	Α
S _{factor}	Softness factor] ′			0.8		
+	$ I_j = 25 \text{ C} dI_F/c$		$I_F = 1 \text{ A}, V_R = 30 \text{ V},$ $dI_F/dt = -50 \text{ A/}\mu\text{s}$		40	55	ns
t _{rr}	Reverse recovery time	T _j = 125 °C	$I_f = 125 ^{\circ}\text{C}$ $I_F = 10 \text{A}, V_R = 400 \text{V}, \ dI_F/dt = -200 \text{A/µs}$		80		110
t _{fr}	Forward recovery time	T _j = 25 °C	I _F = 10 A, V _{FR} = 3 V,			180	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$dI_F/dt = 100 \text{ A}, V_{FR} = 3 \text{ V},$		4.5	7	V

Figure 1. Conduction losses versus average current

Figure 2. Forward voltage drop versus forward current (typical values)



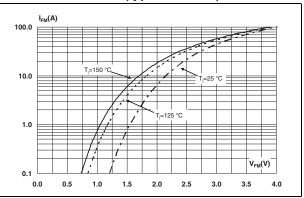
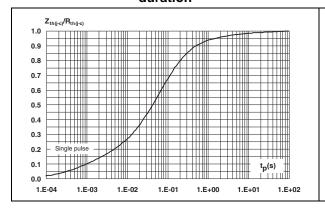
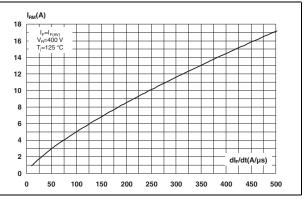


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)

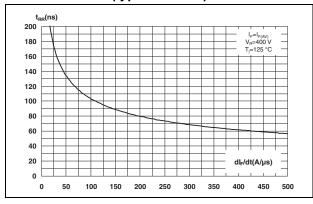




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Figure 5. Reverse recovery time versus dl_F/dt (typical values)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)



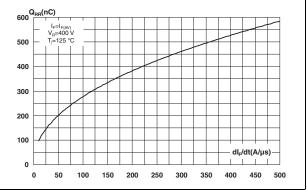
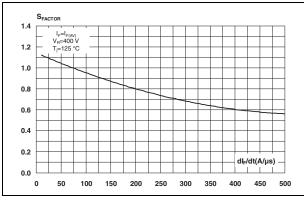
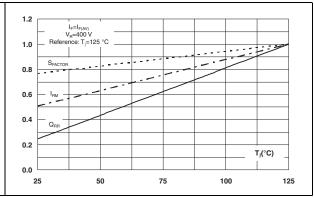


Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values)

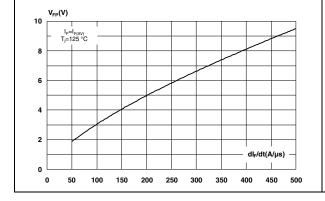
Figure 8. Relative variations of dynamic parameters versus junction temperature

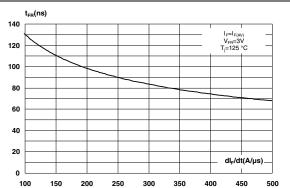




dl_F/dt (typical values)

Figure 9. Transient peak forward voltage versus Figure 10. Forward recovery time versus dl_F/dt (typical values)





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C(pF)

100

100

100

100

V_R(V)

1

1 10 100 1000

Figure 11. Junction capacitance versus reverse voltage applied (typical values)

Package information STTH1008DTI

2 Package information

• Epoxy meets UL94, V0

• Cooling method: by conduction (C)

Recommended torque: 0.4 to 0.6 N·m

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Figure 12. TO-220AC ins dimension definitions

Table 6. TO-220AC ins dimension values

	Dimensions							
Ref.	f. Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	15.20		15.90	0.598		0.625		
a1		3.75			0.147			
a2	13.00		14.00	0.511		0.551		
В	10.00		10.40	0.393		0.409		
b1	0.61		0.88	0.024		0.034		
b2	1.23		1.32	0.048		0.051		
С	4.40		4.60	0.173		0.181		
c1	0.49		0.70	0.019		0.027		
c2	2.40		2.72	0.094		0.107		
е	4.80		5.40	0.189		0.212		
F	6.20		6.60	0.244		0.259		
ØI	3.75		3.85	0.147		0.151		
14	15.80	16.40	16.80	0.622	0.646	0.661		
L	2.65		2.95	0.104		0.116		
12	1.14		1.70	0.044		0.066		
М		2.60			0.102			

Ordering information STTH1008DTI

3 Ordering information

Table 7. Ordering information

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH1008DTI	STTH1008DTI	TO-220AC insulated	2.3 g	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
05-Mar-2013	1	Initial release.

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